

# SKKT 213, SKKH 213



## Thyristor / Diode Modules

SKKH 213

SKKT 213

### Features

- Heat transfer through aluminium nitride ceramic isolated metal baseplate
- Chip soldered on direct copper bonded  $\text{Al}_2\text{O}_3$  ceramic
- Thyristor with amplifying gate
- UL recognized, file no. E 63 532

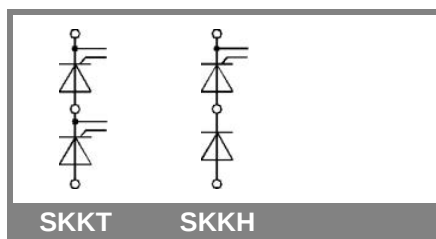
### Typical Applications

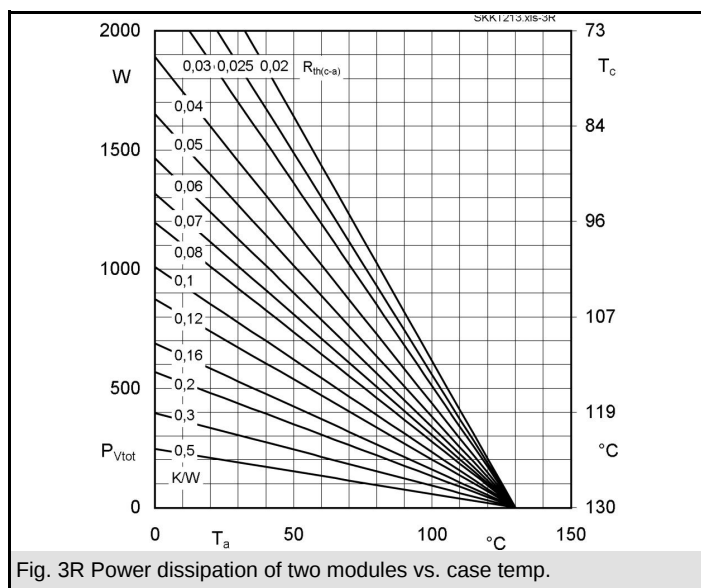
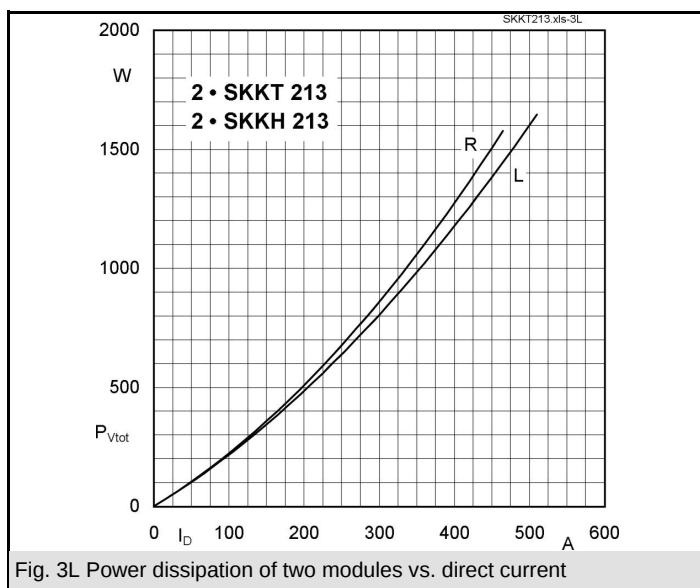
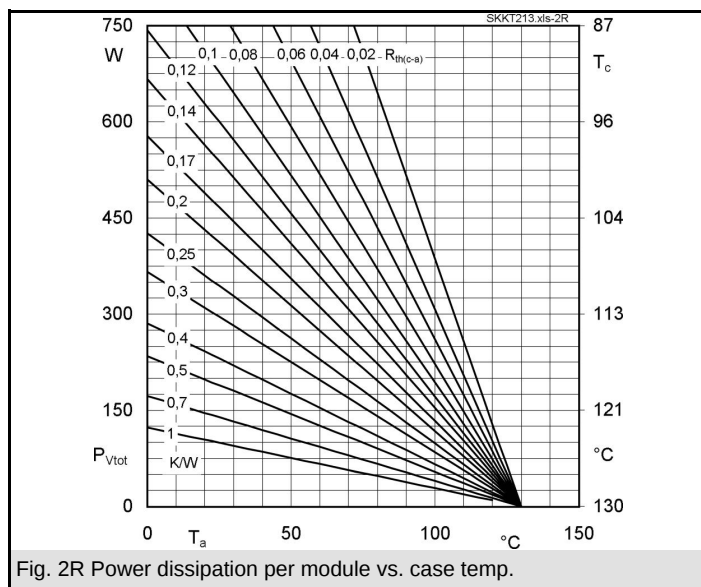
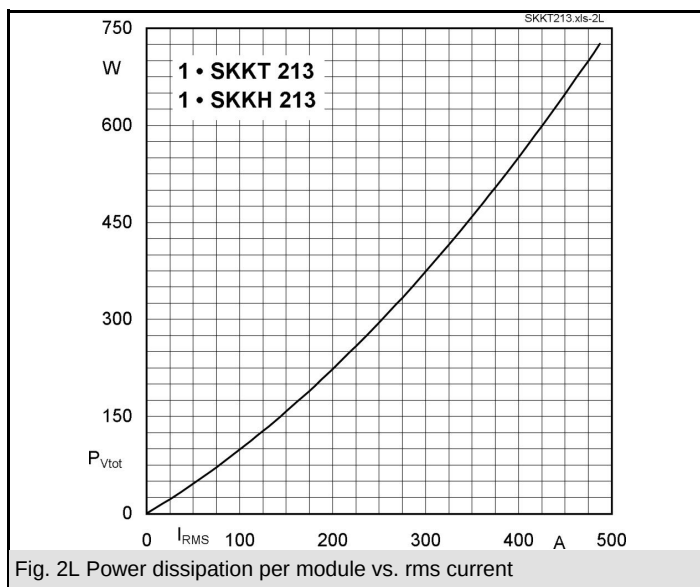
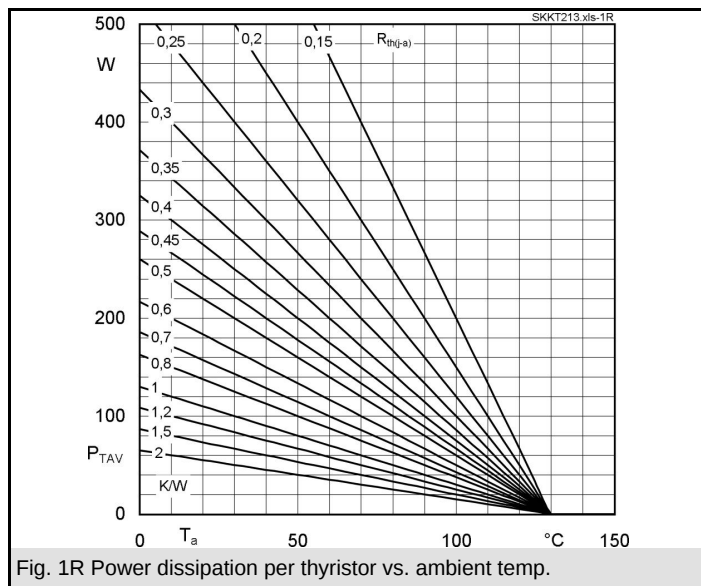
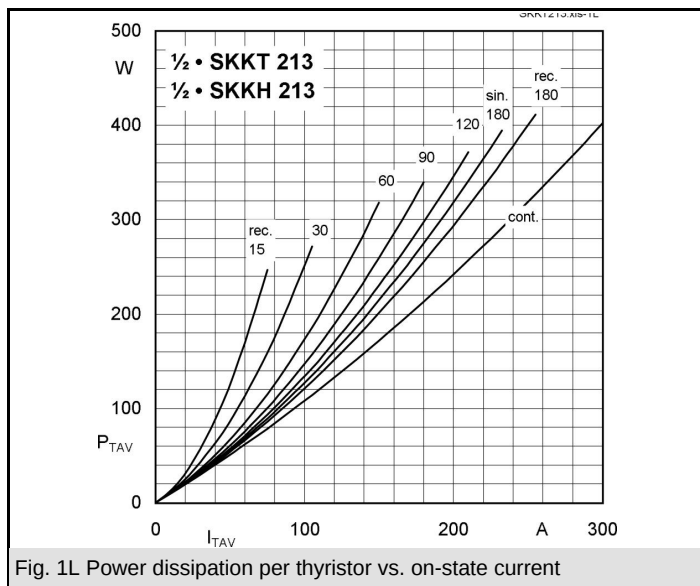
- DC motor control (e. g. for machine tools)
- AC motor starters
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

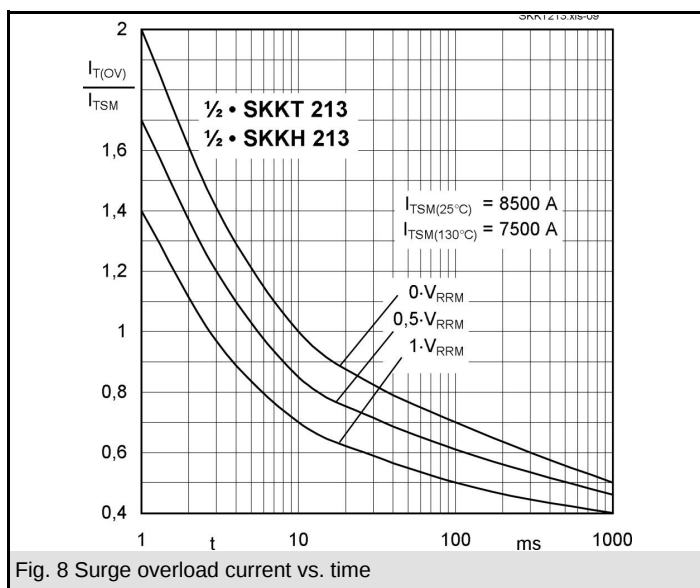
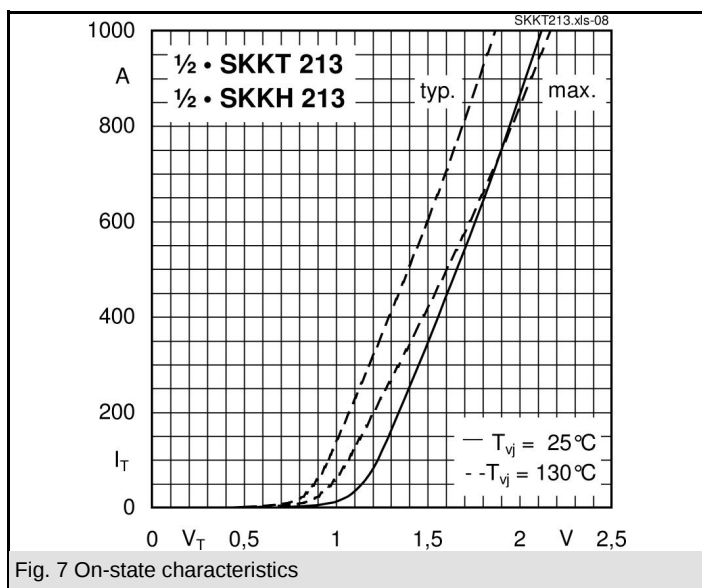
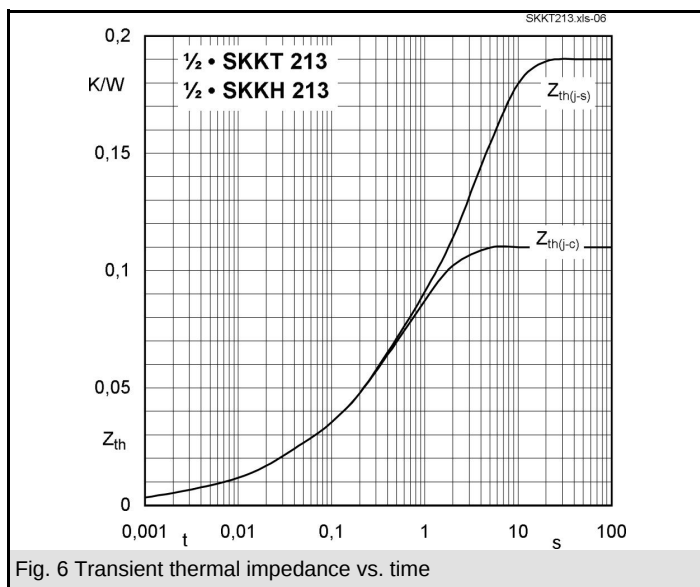
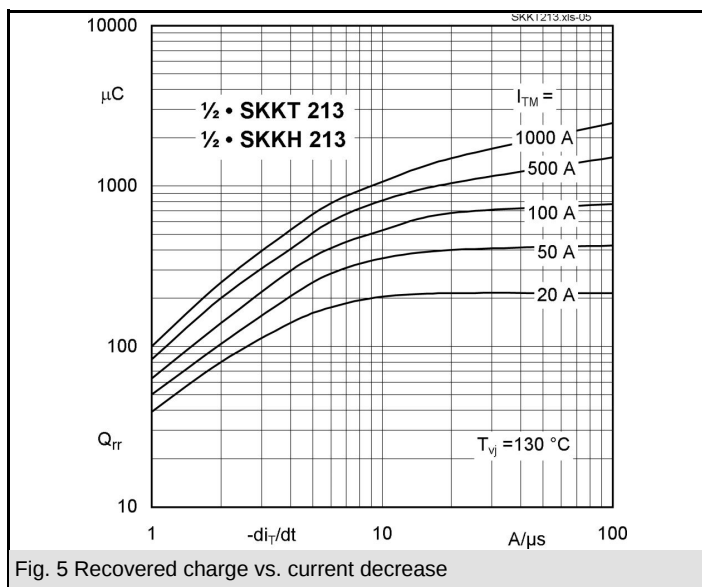
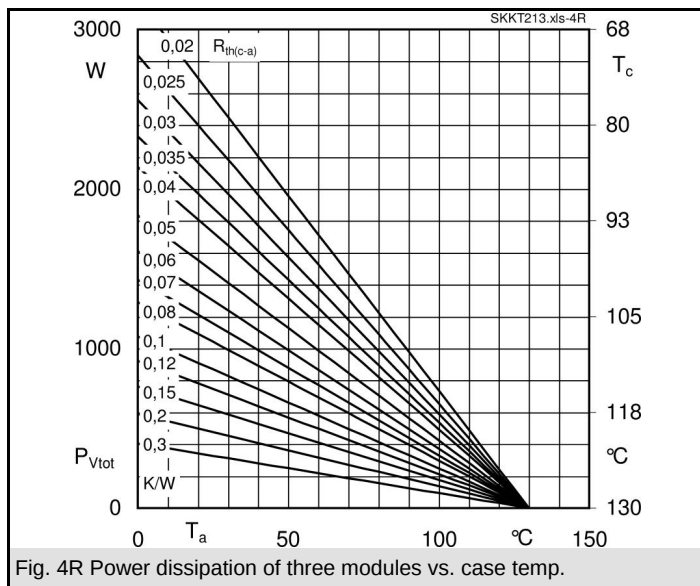
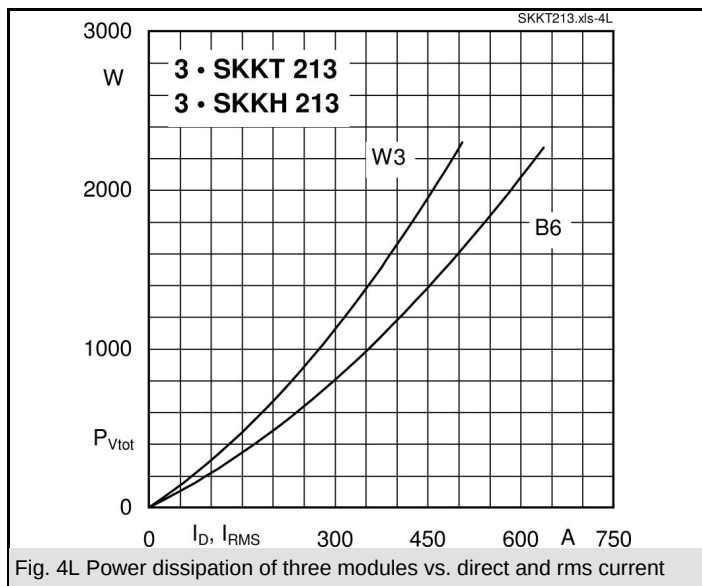
- 1) See the assembly instructions
- 2) The screws must be lubricated
- 3)  $V_{\text{isol}}$  1 s / 1 min = 4800 / 4000 V

| $V_{\text{RSM}}$<br>V | $V_{\text{RRM}}, V_{\text{DRM}}$<br>V | $I_{\text{TRMS}} = 370 \text{ A}$ (maximum value for continuous operation)<br>$I_{\text{TAV}} = 213 \text{ A}$ (sin. 180; $T_c = 90^\circ \text{C}$ ) |              |  |
|-----------------------|---------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|--|
| 900                   | 800                                   | SKKT 213/08D                                                                                                                                          |              |  |
| 1300                  | 1200                                  | SKKT 213/12E                                                                                                                                          | SKKH 213/12E |  |
| 1500                  | 1400                                  | SKKT 213/14E                                                                                                                                          | SKKH 213/14E |  |
| 1700                  | 1600                                  | SKKT 213/16E                                                                                                                                          | SKKH 213/16E |  |
| 1900                  | 1800                                  | SKKT 213/18E                                                                                                                                          | SKKH 213/18E |  |

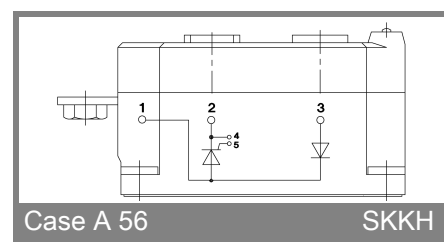
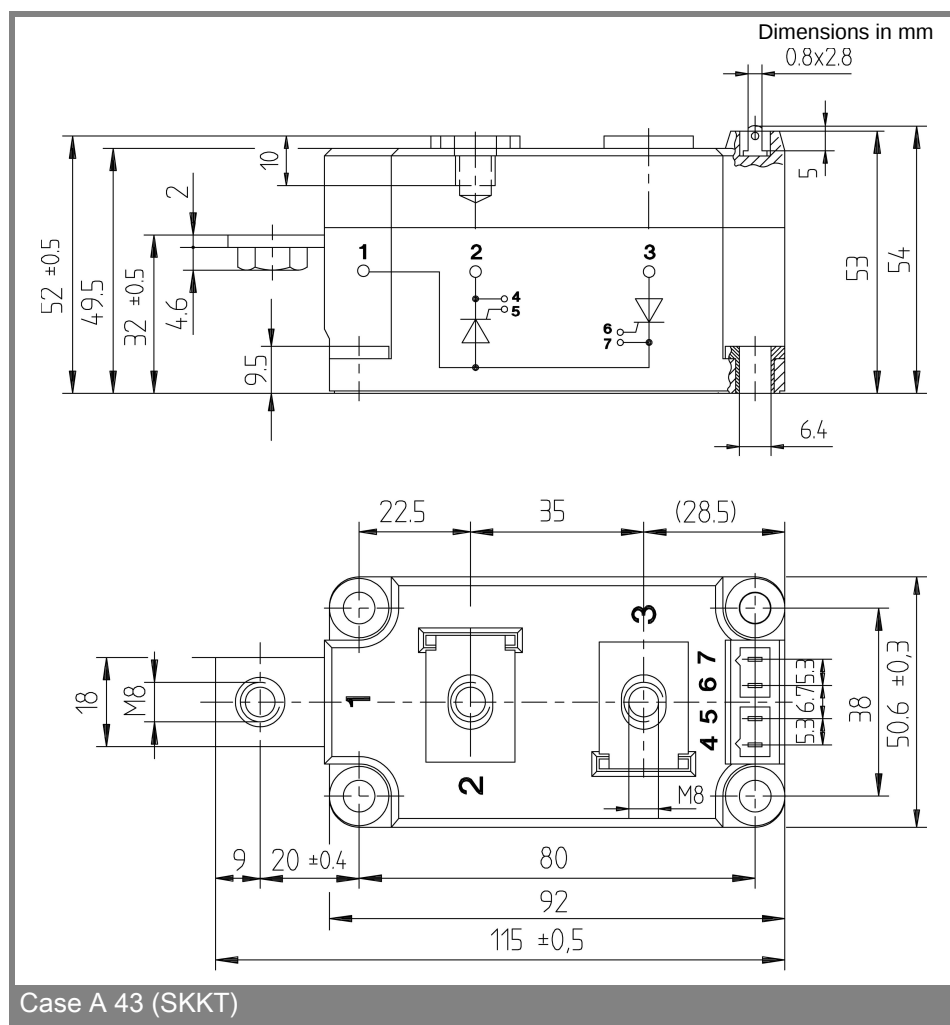
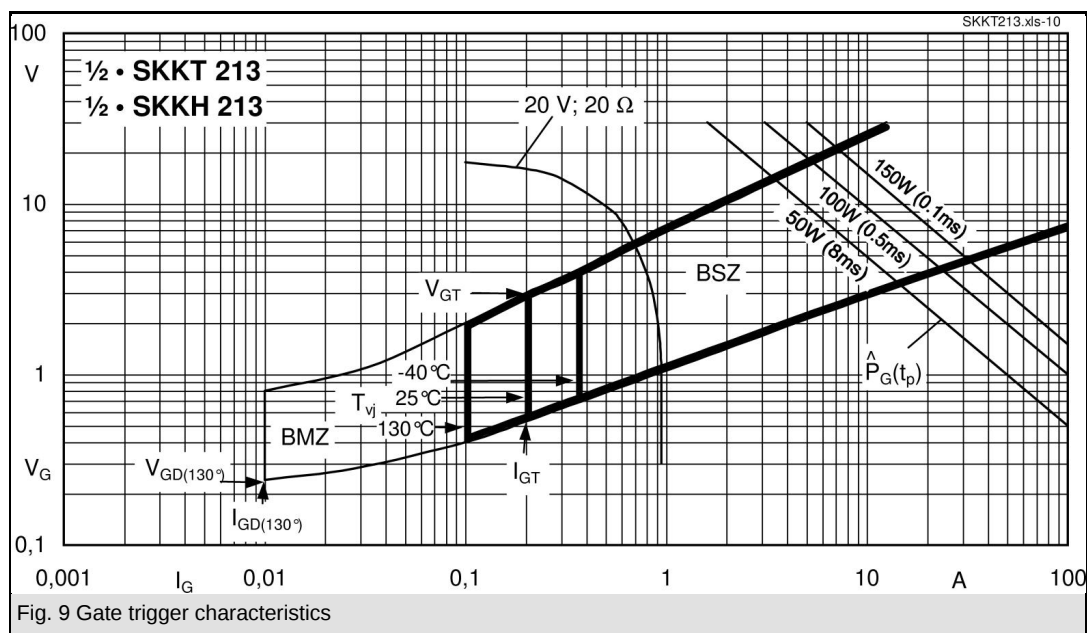
| Symbol                         | Conditions                                                                                          | Values             | Units             |
|--------------------------------|-----------------------------------------------------------------------------------------------------|--------------------|-------------------|
| $I_{\text{TAV}}$               | sin. 180; $T_c = 85 (100)^\circ \text{C}$                                                           | 230 (173)          | A                 |
| $I_{\text{D}}$                 | P16/200F; $T_a = 35^\circ \text{C}$ ; B2 / B6                                                       | 354 / 456          | A                 |
| $I_{\text{RMS}}$               | P16/200F; $T_a = 35^\circ \text{C}$ ; W1 / W3                                                       | 425 / 3 * 360      | A                 |
| $I_{\text{TSM}}$               | $T_{vj} = 25^\circ \text{C}$ ; 10 ms                                                                | 8500               | A                 |
|                                | $T_{vj} = 130^\circ \text{C}$ ; 10 ms                                                               | 7500               | A                 |
| $i^2t$                         | $T_{vj} = 25^\circ \text{C}$ ; 8,3 ... 10 ms                                                        | 361000             | A <sup>2</sup> s  |
|                                | $T_{vj} = 130^\circ \text{C}$ ; 8,3 ... 10 ms                                                       | 281000             | A <sup>2</sup> s  |
| $V_T$                          | $T_{vj} = 25^\circ \text{C}$ ; $I_T = 750 \text{ A}$                                                | max. 1,9           | V                 |
| $V_{T(\text{TO})}$             | $T_{vj} = 130^\circ \text{C}$                                                                       | 0,95               | V                 |
| $r_T$                          | $T_{vj} = 130^\circ \text{C}$                                                                       | 1,3                | m $\Omega$        |
| $I_{\text{DD}}, I_{\text{RD}}$ | $T_{vj} = 130^\circ \text{C}$ ; $V_{\text{RD}} = V_{\text{RRM}}$ ; $V_{\text{DD}} = V_{\text{DRM}}$ | max. 50            | mA                |
| $t_{\text{gd}}$                | $T_{vj} = 25^\circ \text{C}$ ; $I_G = 1 \text{ A}$ ; $di_G/dt = 1 \text{ A}/\mu\text{s}$            | 1                  | $\mu\text{s}$     |
| $t_{\text{gr}}$                | $V_D = 0,67 * V_{\text{DRM}}$                                                                       | 2                  | $\mu\text{s}$     |
| $(di/dt)_{\text{cr}}$          | $T_{vj} = 130^\circ \text{C}$                                                                       | max. 250           | A/ $\mu\text{s}$  |
| $(dv/dt)_{\text{cr}}$          | $T_{vj} = 130^\circ \text{C}$ ; SKK ...D / SKK ...E                                                 | max. 500 / 1000    | V/ $\mu\text{s}$  |
| $t_q$                          | $T_{vj} = 130^\circ \text{C}$                                                                       | 50 ... 150         | $\mu\text{s}$     |
| $I_H$                          | $T_{vj} = 25^\circ \text{C}$ ; typ. / max.                                                          | 150 / 500          | mA                |
| $I_L$                          | $T_{vj} = 25^\circ \text{C}$ $R_G = 33 \Omega$ ; typ. / max.                                        | 300 / 2000         | mA                |
| $V_{\text{GT}}$                | $T_{vj} = 25^\circ \text{C}$ ; d.c.                                                                 | min. 3             | V                 |
| $I_{\text{GT}}$                | $T_{vj} = 25^\circ \text{C}$ ; d.c.                                                                 | min. 200           | mA                |
| $V_{\text{GD}}$                | $T_{vj} = 130^\circ \text{C}$ ; d.c.                                                                | max. 0,25          | V                 |
| $I_{\text{GD}}$                | $T_{vj} = 130^\circ \text{C}$ ; d.c.                                                                | max. 10            | mA                |
| $R_{\text{th(j-c)}}$           | cont.; per thyristor / per module                                                                   | 0,11 / 0,055       | K/W               |
| $R_{\text{th(j-c)}}$           | sin. 180; per thyristor / per module                                                                | 0,115 / 0,057      | K/W               |
| $R_{\text{th(j-c)}}$           | rec. 120; per thyristor / per module                                                                | 0,125 / 0,0625     | K/W               |
| $R_{\text{th(c-s)}}$           | per thyristor / per module                                                                          | 0,08 / 0,04        | K/W               |
| $T_{vj}$                       |                                                                                                     | - 40 ... + 130     | $^\circ \text{C}$ |
| $T_{\text{stg}}$               |                                                                                                     | - 40 ... + 130     | $^\circ \text{C}$ |
| $V_{\text{isol}}$              | a. c. 50 Hz; r.m.s.; 1 s / 1 min.                                                                   | 3600 / 3000        | V~                |
| $M_s$                          | to heatsink                                                                                         | $5 \pm 15 \%^{1)}$ | Nm                |
| $M_t$                          | to terminals                                                                                        | $9 \pm 15 \%^{2)}$ | Nm                |
| $a$                            |                                                                                                     | $5 * 9,81$         | m/s <sup>2</sup>  |
| $m$                            | approx.                                                                                             | 400                | g                 |
| Case                           | SKKT                                                                                                | A 43               |                   |
|                                | SKKH                                                                                                | A 56               |                   |







# SKKT 213, SKKH 213



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